**Vishay Semiconductors** 

## Low Current Mini SMD LED



#### DESCRIPTION

The new low current MiniLED Series have been designed in a small white SMT package. The feature of the device is the very small package 2.3 mm x 1.3 mm x 1.4 mm and the low forward current. The MiniLED is an obvious solution for small-scale, high-power products that are expected to work reliability in an arduous environment. This is often the case in automotive and industrial application.

### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD MiniLED
- Product series: low current
- Angle of half intensity: ± 60°

### FEATURES

- SMD LEDs with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- · IR reflow soldering
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packing unit  $I_{Vmax}/I_{Vmin} \leq 2.0, \mbox{ optional} \leq 1.6$
- Lead (Pb)-free device

#### **APPLICATIONS**

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- · Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
TLMS2000	Red, $I_V = 4.5 \text{ mcd}$ (typ.)	AllnGaP on GaAs
TLMO2000	Orange, I <sub>V</sub> = 9.0 mcd (typ.)	AllnGaP on GaAs
TLMY2000	Yellow, I <sub>V</sub> = 7.1 mcd (typ.)	AllnGaP on GaAs
TLMK2000	Amber, I <sub>V</sub> = 10.0 mcd (typ.)	AllnGaP on GaAs



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ABSOLUTE MAXIMUM RATINGS <sup>1)</sup> TLMS200. ,TLMO200. ,TLMY200, TLMK2000.						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage <sup>2)</sup>		V <sub>R</sub>	5	V		
DC Forward current	$T_{amb} \le 100 \ ^{\circ}C$	١ <sub>F</sub>	15	mA		
Surge forward current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	0.1	A		
Power dissipation	$T_{amb} \le 100 \ ^{\circ}C$	P <sub>V</sub>	40	mW		
Junction temperature		Тj	125	°C		
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C		
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C		
Soldering temperature	according to IPC 9501	T <sub>sd</sub>	245	°C		
Thermal resistance junction/ ambient	mounted on PC board (pad size > 5 mm <sup>2</sup> )	R <sub>thJA</sub>	580	K/W		

#### Note:

<sup>(1)</sup>  $T_{amb} = 25 \text{ °C}$ , unless otherwise specified <sup>(2)</sup> Driving the LED in reverse direction is suitable for a short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> RED, TLMS200.						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	I <sub>F</sub> = 2 mA	I <sub>V</sub>	2	4.5		mcd
Dominant wavelength	I <sub>F</sub> = 2 mA	λ <sub>d</sub>		630		nm
Peak wavelength	I <sub>F</sub> = 2 mA	λ <sub>p</sub>		643		nm
Angle of half intensity	I <sub>F</sub> = 2 mA	φ		± 60		deg
Forward voltage	I <sub>F</sub> = 2 mA	V <sub>F</sub>		1.8	2.2	V
Reverse voltage	I <sub>R</sub> = 10 μA	V <sub>R</sub>	5			V
Junction capacitance	V <sub>R</sub> = 0, f = 1 MHz	Cj		15		pF

Note:

 $^{(1)}$  T<sub>amb</sub> = 25 °C, unless otherwise specified  $^{(2)}$  in one packing unit I<sub>Vmax</sub>/I<sub>Vmin</sub>  $\leq 2.0$ 

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> ORANGE, TLMO200.						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity 2)	I <sub>F</sub> = 2 mA	Ι <sub>V</sub>	4	9		mcd
Dominant wavelength	I <sub>F</sub> = 2 mA	λ <sub>d</sub>	598	605	611	nm
Peak wavelength	I <sub>F</sub> = 2 mA	λρ		610		nm
Angle of half intensity	I <sub>F</sub> = 2 mA	φ		± 60		deg
Forward voltage	I <sub>F</sub> = 2 mA	V <sub>F</sub>		1.8	2.2	V
Reverse voltage	I <sub>R</sub> = 10 μA	V <sub>R</sub>	5			V
Junction capacitance	V <sub>R</sub> = 0, f = 1 MHz	Cj		15		pF

Note:

<sup>(1)</sup>  $T_{amb} = 25$  °C, unless otherwise specified <sup>(2)</sup> in one packing unit  $I_{Vmax}/I_{Vmin} \le 2.0$ 



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OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> YELLOW, TLMY200.						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	I <sub>F</sub> = 2 mA	۱ <sub>V</sub>	3.2	7.1		mcd
Dominant wavelength	I <sub>F</sub> = 2 mA	$\lambda_d$	581	588	594	nm
Peak wavelength	I <sub>F</sub> = 2 mA	λ <sub>p</sub>		590		nm
Angle of half intensity	I <sub>F</sub> = 2 mA	φ		± 60		deg
Forward voltage	I <sub>F</sub> = 2 mA	V <sub>F</sub>		1.8	2.2	V
Reverse voltage	I <sub>R</sub> = 10 μA	V <sub>R</sub>	5			V
Junction capacitance	V <sub>R</sub> = 0, f = 1 MHz	Cj		15		pF

Note:

 $^{(1)}$  T<sub>amb</sub> = 25 °C, unless otherwise specified  $^{(2)}$  in one packing unit I<sub>Vmax</sub>/I<sub>Vmin</sub>  $\leq$  2.0

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> AMBER, TLMK200.						
Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Luminous intensity 2)	I <sub>F</sub> = 2 mA	Ι <sub>V</sub>	6.3	16		mcd
Dominant wavelength	I <sub>F</sub> = 2 mA	λ <sub>d</sub>	612	622	624	nm
Peak wavelength	I <sub>F</sub> = 2 mA	λρ		615		nm
Angle of half intensity	I <sub>F</sub> = 2 mA	φ		± 60		deg
Forward voltage	I <sub>F</sub> = 2 mA	V <sub>F</sub>		1.8	2.2	V
Reverse voltage	I <sub>R</sub> = 10 μA	V <sub>R</sub>	5			V
Junction capacitance	V <sub>R</sub> = 0, f = 1 MHz	Cj		15		pF

Note:

 $^{1)}$  T\_{amb} = 25 °C, unless otherwise specified  $^{2)}$  in one packing unit  $I_{Vmax}/I_{Vmin} \leq 2.0$ 

### FORWARD VOLTAGE CLASSIFICATION

GROUP	FORWARD VOLTAGE (V)			
	MIN.	MAX.		
1	1.85	2.25		
2	2.15	2.55		

COLOR CLASSIFICATION								
GROUP		DO	MINA	NT WA	VELEN	IGTH (I	M)	
	R	ED		OFT ANGE	YEL	LOW	АМ	BER
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX
1	611	618	598	601	581	584		
2	614	622	600	603	583	586		
3			602	605	585	588		
4			604	607	587	590		
5			606	609	589	592		
6			608	611	591	594		
7							610	613
8							612	616
9							615	620
10							619	624

LUMINOUS INTENSITY CLASSIFICATION						
GROUP	LUMINOUS INTENSITY (MCD)					
	MIN.	MAX.				
Mb	2.0	3.2				
Na	2.5	4.0				
Nb	3.2	5.0				
Pa	4.0	6.3				
Pb	5.0	8.0				
Qa	6.3	10.0				
Qb	8.0	12.5				
Ra	10.0	16.0				
Rb	12.5	20.0				
Sa	16.0	25.0				
Sb	20.0	32.0				

#### Document Number 83185 Rev. 1.4, 24-Sep-07

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### TYPICAL CHARACTERISTICS

 $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

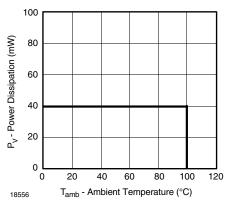


Figure 1. Power Dissipation vs. Ambient Temperature

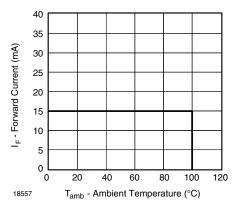


Figure 2. Forward Current vs. Ambient Temperature

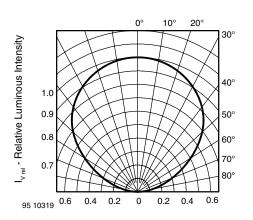


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

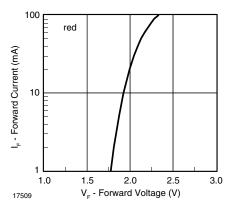


Figure 4. Forward Current vs. Forward Voltage

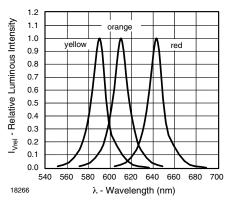


Figure 5. Relative Intensity vs. Wavelength

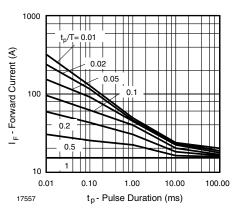


Figure 6. Forward Current vs. Pulse Length





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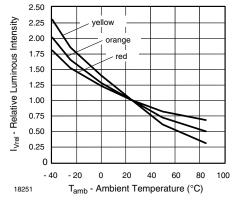


Figure 7. Rel. Luminous Intensity vs. Ambient Temperature

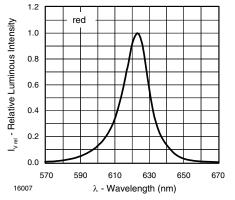


Figure 9. Relative Luminous Intensity vs. Wavelength

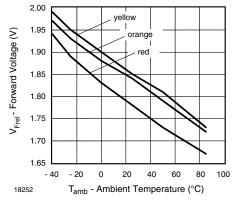
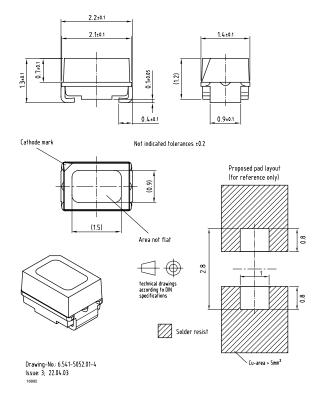


Figure 8. Forward Voltage vs. Ambient Temperature

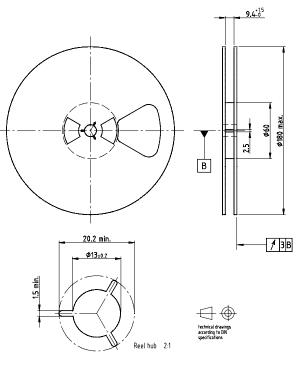
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### PACKAGE DIMENSIONS



#### **REEL DIMENSIONS** in millimeters

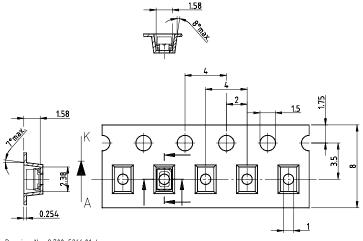


Drawing-No.: 9.800-5051.V5-4 Issue: 1; 25.07.02



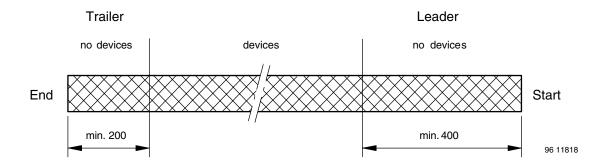
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### TAPE DIMENSIONS in millimeters



Drawing-No.: 9.700-5266.01-4 Issue: 1; 05.06.02

#### LEADER AND TRAILER in millimeters



GS08 = 3000 pcs



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### **COVER TAPE PEEL STRENGTH**

According to DIN EN 60286-3 0.1 to 1.3 N  $300 \pm 10 \text{ mm/min}$  $165^{\circ} - 180^{\circ}$  peel angle

### LABEL

#### Standard bar code labels for finished goods

The standard bar code labels are product labels and used for identification of goods. The finished goods are packed in final packing area. The standard packing units are labeled with standard bar code labels before transported as finished goods to warehouses. The labels are on each packing unit and contain Vishay Semiconductor GmbH specific data.

### Vishay Semiconductor GmbH standard bar code product label (finished goods)

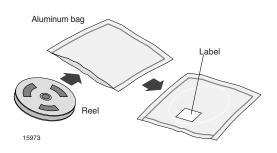
Plain Writting	Abbreviation	Length
Item-description	-	18
Item-number	INO	8
Selection-code	SEL	3
LOT-/serial-number	BATCH	10
Data-code	COD	3 (YWW)
Plant-code	PTC	2
Quantity	QTY	8
Accepted by:	ACC	-
Packed by:	PCK	-
Mixed code indicator	MIXED CODE	-
Origin	XXXXXXX <sup>+</sup>	Company logo
Long Bar Code Top	Туре	Length
Item-number	Ν	8
Plant-code	Ν	2
Sequence-number	Х	3
Quantity	Ν	8
Total length	-	21
Short Bar Code Bottom	Туре	Length
Selection-code	Х	3
Data-code	Ν	3
Batch-number	Х	10
Filter	-	1
Total length	-	17

### **Vishay Semiconductors**



### **DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



### **FINAL PACKING**

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

#### **RECOMMENDED METHOD OF STORAGE**

Dry box storage is recommended as soon as the aluminium bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity  $\leq$  60 % RH max.

After more than 1 year under these conditions moisture content will be too high for reflow soldering.

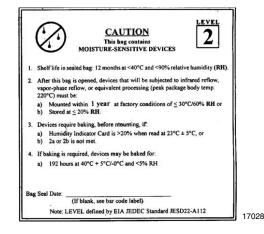
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/ - 0 °C and < 5 % RH (dry air/ nitrogen) or

96 h at 60 °C +5 °C and < 5 % RH for all device containers or

24 h at 100 °C +5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2 label is included on all dry bags.



Example of JESD22-A112 level 2 label

### **ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

### VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

### **Vishay Semiconductors**



### **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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